High-speed switching diodes Rev. 8 — 18 November 2010

Product data sheet

1. **Product profile**

1.1 General description

High-speed switching diodes, encapsulated in small Surface-Mounted Device (SMD) plastic packages.

Table 1. **Product overview**

Type number	Package	e		Configuration	Package
	NXP	JEITA	JEDEC	EDEC configura	
BAV99	SOT23	-	TO-236AB	dual series	small
BAV99S	SOT363	SC-88	-	quadruple; 2 series	very small
BAV99W	SOT323	SC-70	-	dual series	very small

1.2 Features and benefits

- High switching speed: $t_{rr} \le 4$ ns
- Low leakage current
- Small SMD plastic packages

1.3 Applications

- High-speed switching
- General-purpose switching

1.4 Quick reference data

- Low capacitance: $C_d \le 1.5 \text{ pF}$
- Reverse voltage: $V_R \le 100 \text{ V}$
- AEC-Q101 qualified
- Reverse polarity protection

Quick reference data					
Parameter	Conditions	Min	Тур	Мах	Unit
)					
reverse current	V _R = 80 V	-	-	0.5	μA
reverse voltage		-	-	100	V
reverse recovery time		<u>[1]</u> _	-	4	ns
	Parameter reverse current reverse voltage	Parameter Conditions reverse current V _R = 80 V reverse voltage	Parameter Conditions Min reverse current V _R = 80 V - reverse voltage -	Parameter Conditions Min Typ reverse current V _R = 80 V - - reverse voltage - -	Parameter Conditions Min Typ Max reverse current V _R = 80 V - - 0.5 reverse voltage - - 100

[1] When switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ; measured at I_R = 1 mA.



High-speed switching diodes

2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
BAV99;	BAV99W		
1	anode (diode 1)		
2	cathode (diode 2)	3	3
3	cathode (diode 1), anode (diode 2)	2	
BAV99S			
1	anode (diode 1)		
2	cathode (diode 2)		6 5 4
3	cathode (diode 3), anode (diode 4)	0	
4	anode (diode 3)		本 平
5	cathode (diode 4)		1 2 3
6	cathode (diode 1), anode (diode 2)		006aab101

3. Ordering information

Type number	Package		
	Name	Description	Version
BAV99	-	plastic surface-mounted package; 3 leads	SOT23
BAV99S	SC-88	plastic surface-mounted package; 6 leads	SOT363
BAV99W	SC-70	plastic surface-mounted package; 3 leads	SOT323

4. Marking

Table 5. Marking codes	
Type number	Marking code ^[1]
BAV99	A7*
BAV99S	K1*
BAV99W	A7*

[1] * = placeholder for manufacturing site code

BAV99_SER
Product data sheet

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5. Limiting values

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
V _{RRM}	repetitive peak reverse voltage		-	100	V
V _R	reverse voltage		-	100	V
I _F	forward current				
	BAV99		[1] _	215	mA
			[2] _	125	mA
BAV99S			[1] _	200	mA
	BAV99W		<u>[1]</u> _	150	mA
			[2] _	130	mA
I _{FRM}	repetitive peak forward current		-	500	mA
I _{FSM}	non-repetitive peak	square wave	[3]		
	forward current	t _p = 1 μs	-	4	А
		t _p = 1 ms	-	1	А
		t _p = 1 s	-	0.5	А
P _{tot}	total power dissipation		<u>[1][4]</u>		
	BAV99	$T_{amb} \le 25 \ ^{\circ}C$	-	250	mW
	BAV99S	T _{sp} ≤ 85 °C	[5]	250	mW
	BAV99W	$T_{amb} \le 25 \ ^{\circ}C$	-	200	mW
Per device					
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

[1] Single diode loaded.

[2] Double diode loaded.

[3] $T_i = 25 \circ C$ prior to surge.

[4] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[5] Soldering points at pins 2, 3, 5 and 6.

High-speed switching diodes

6. Thermal characteristics

Table 7.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	<u>[1][2]</u>			
	BAV99		-	-	500	K/W
	BAV99W		-	-	625	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point					
	BAV99		-	-	360	K/W
	BAV99S		[3] _	-	260	K/W
	BAV99W		-	-	300	K/W

[1] Single diode loaded.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[3] Soldering points at pins 2, 3, 5 and 6.

7. Characteristics

Table 8. Characteristics

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Per diode)					
V _F forward voltage		I _F = 1 mA	-	-	715	mV
		I _F = 10 mA	-	-	855	mV
		I _F = 50 mA	-	-	1	V
		I _F = 150 mA	-	-	1.25	V
I _R	R reverse current	V _R = 25 V	-	-	30	nA
		V _R = 80 V	-	-	0.5	μ A
		V _R = 25 V; T _j = 150 °C	-	-	30	μA
		V _R = 80 V; T _j = 150 °C	-	-	50	μA
C _d	diode capacitance	f = 1 MHz; V _R = 0 V	-	-	1.5	pF
t _{rr}	reverse recovery time		<u>[1]</u> _	-	4	ns
V _{FR}	forward recovery voltage		[2]	-	1.75	V

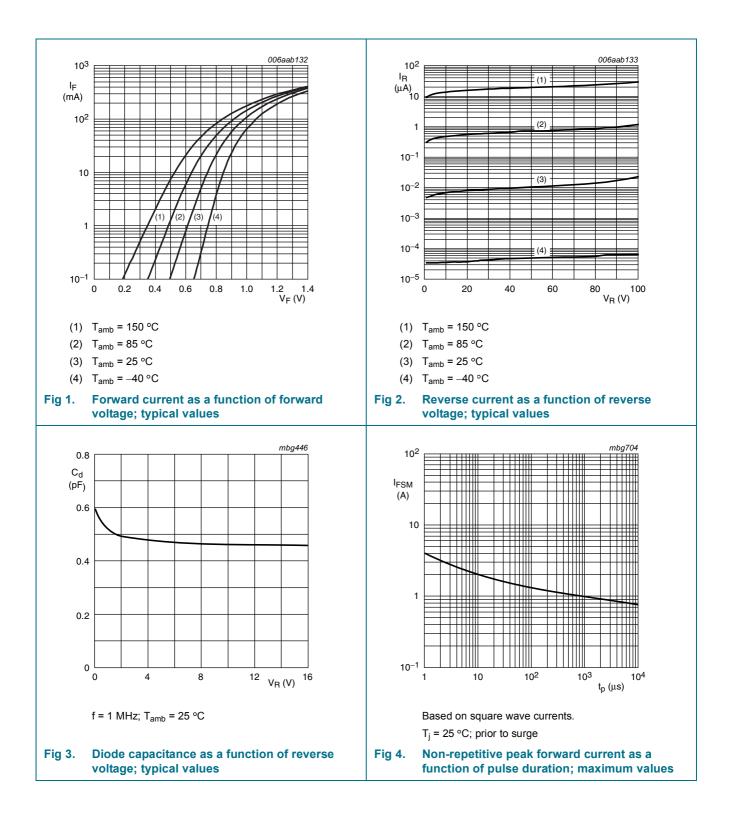
[1] When switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ; measured at I_R = 1 mA.

[2] When switched from $I_F = 10 \text{ mA}$; $t_r = 20 \text{ ns}$.

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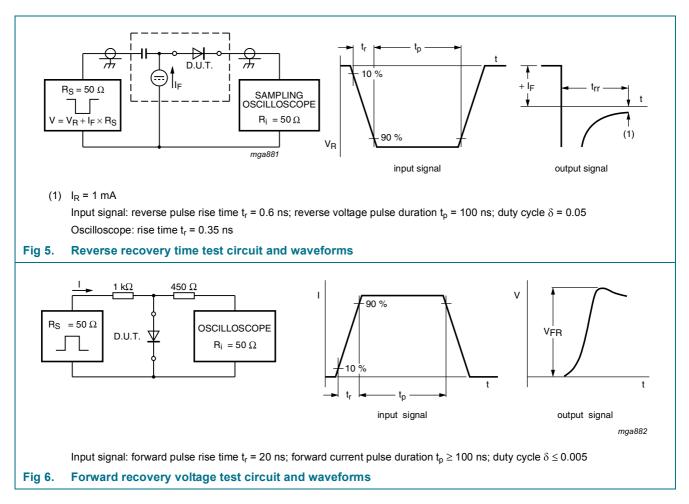
BAV99 series

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8. Test information

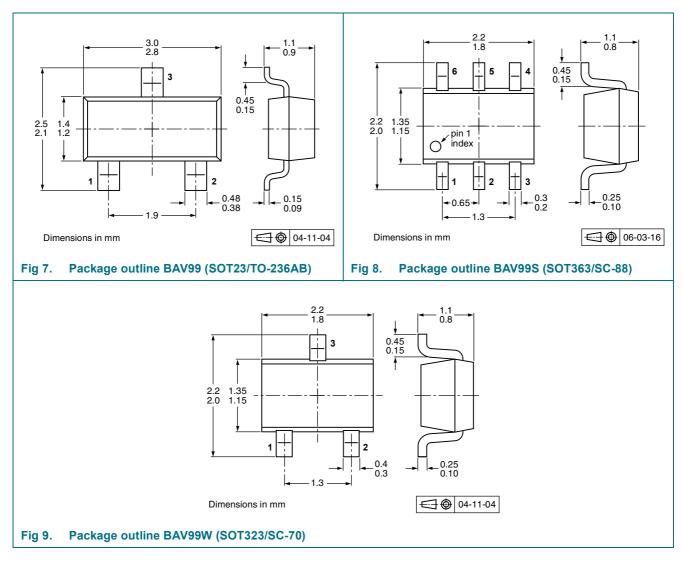


8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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9. Package outline



10. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing q	uantity
			3000	10000
BAV99	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235
BAV99S	SOT363	4 mm pitch, 8 mm tape and reel; T1 [2]	-115	-135
		4 mm pitch, 8 mm tape and reel; T2 [3]	-125	-165
BAV99W	SOT323	4 mm pitch, 8 mm tape and reel	-115	-135

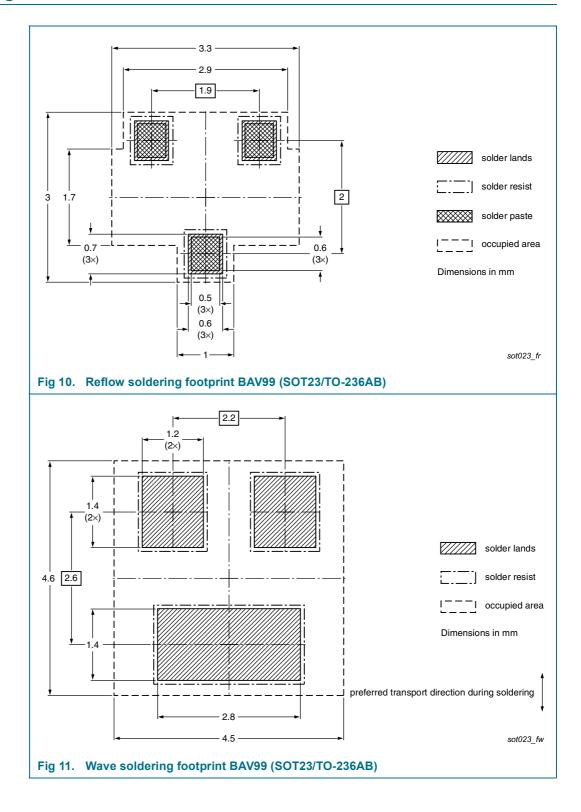
[1] For further information and the availability of packing methods, see Section 14.

[2] T1: normal taping

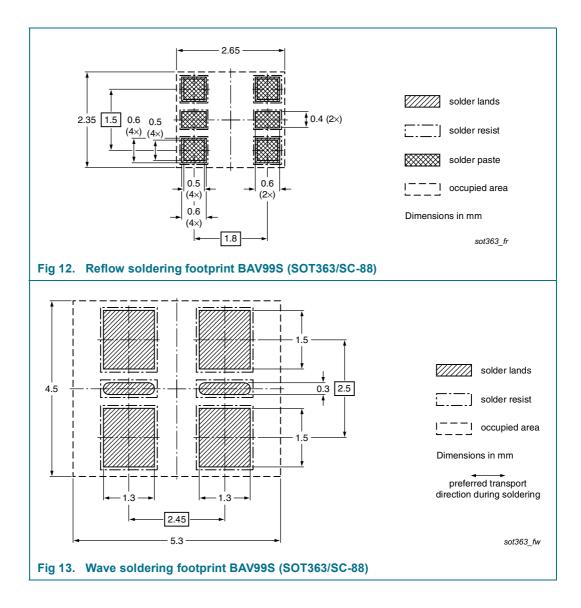
[3] T2: reverse taping

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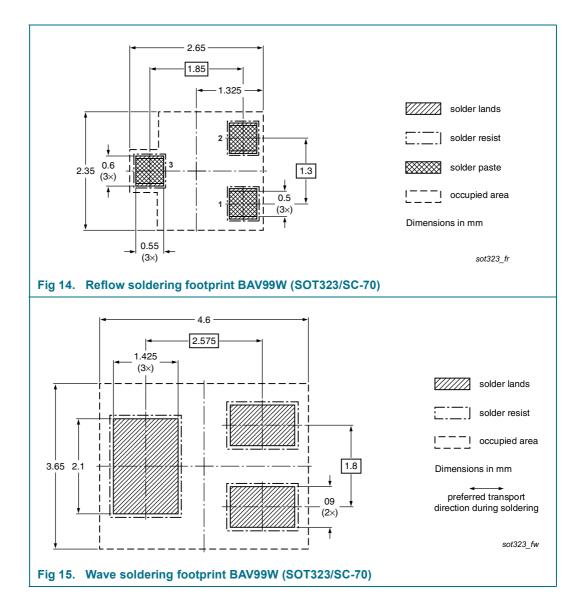
11. Soldering



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12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAV99_SER_8	20101118	Product data sheet	-	BAV99_SER_7
Modifications:	Section 4 "	<pre>/arking": marking placehold</pre>	er explanation in table	footer updated
	 Section 5 "L 	imiting values": Ptot condition	on for BAV99S corrected	d
	Section 13	<u>'Legal information</u> ": updated	I	
BAV99_SER_7	20100414	Product data sheet	-	BAV99_SER_6
BAV99_SER_6	20100310	Product data sheet	-	BAV99_SER_5
BAV99_SER_5	20080820	Product data sheet	-	BAV99_4
				BAV99S_3
				BAV99W_4
BAV99_4	20011015	Product specification	-	BAV99_3
BAV99S_3	20010514	Product specification	-	BAV99S_N_2
BAV99W_4	19990511	Product specification	-	BAV99W 3

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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